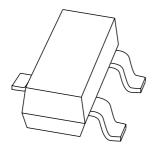
DISCRETE SEMICONDUCTORS

DATA SHEET



BCV26; BCV46 PNP Darlington transistors

Product data sheet Supersedes data of 1999 Apr 08 2004 Jan 13



PNP Darlington transistors

BCV26; **BCV46**

FEATURES

- High current (max. 500 mA)
- Low voltage (max. 60 V)
- Very high DC current gain (min. 10000).

APPLICATIONS

• Where very high amplification is required.

DESCRIPTION

PNP Darlington transistor in a SOT23 plastic package. NPN complements: BCV27 and BCV47.

MARKING

| TYPE NUMBER | MARKING CODE ⁽¹⁾ |
|-------------|-----------------------------|
| BCV26 | FD* |
| BCV46 | FE* |

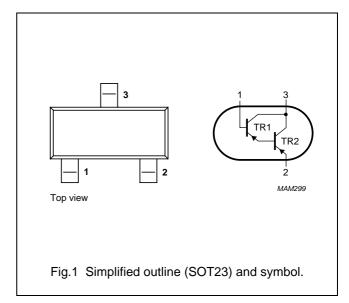
Note

* = p : Made in Hong Kong.
 * = t : Made in Malaysia.

* = W : Made in China.

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | base |
| 2 | emitter |
| 3 | collector |



ORDERING INFORMATION

| TYPE | PACKAGE | | | | |
|--------|---------|--|--|--|--|
| NUMBER | NAME | ME DESCRIPTION VERSIO | | | |
| BCV26 | _ | plastic surface mounted package; 3 leads | | | |
| BCV46 | | | | | |

PNP Darlington transistors

BCV26; BCV46

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------|----------------------------------|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | | | |
| | BCV26 | | _ | -40 | V |
| | BCV46 | | _ | -80 | V |
| V _{CES} | collector-emitter voltage | V _{BE} = 0 | | | |
| | BCV26 | | _ | -30 | V |
| | BCV46 | | _ | -60 | V |
| V _{EBO} | emitter-base voltage | open collector | - | -10 | ٧ |
| I _C | collector current (DC) | | _ | -500 | mA |
| I _{CM} | peak collector current | | _ | -800 | mA |
| I _B | base current (DC) | | _ | -100 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C; note 1 | _ | 250 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | _ | 150 | °C |
| T _{amb} | operating ambient temperature | | -65 | +150 | °C |

Note

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------------|---|------------|-------|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | note 1 | 500 | K/W |

Note

1. Transistor mounted on an FR4 printed-circuit board.

^{1.} Transistor mounted on an FR4 printed-circuit board.

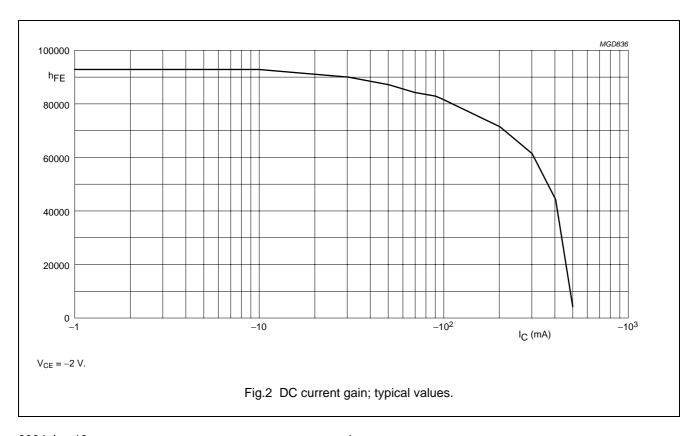
PNP Darlington transistors

BCV26; BCV46

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--------------------|--------------------------------------|---|-------|------|------|------|
| I _{CBO} | collector cut-off current | | | | | |
| | BCV26 | $I_E = 0; V_{CB} = -30 \text{ V}$ | _ | _ | -100 | nA |
| | BCV46 | $I_E = 0; V_{CB} = -60 \text{ V}$ | _ | _ | -100 | nA |
| I _{EBO} | emitter cut-off current | $I_C = 0; V_{EB} = -10 \text{ V}$ | _ | _ | -100 | nA |
| h _{FE} | DC current gain | $I_C = -1 \text{ mA}; V_{CE} = -5 \text{ V}; \text{ (see Fig.2)}$ | | | | |
| | BCV26 | | 4000 | _ | _ | |
| | BCV46 | | 2000 | _ | _ | |
| | DC current gain | $I_C = -10 \text{ mA}; V_{CE} = -5 \text{ V}; \text{ (see Fig.2)}$ | | | | |
| | BCV26 | | 10000 | _ | _ | |
| | BCV46 | | 4000 | _ | _ | |
| | DC current gain | $I_C = -100 \text{ mA}; V_{CE} = -5 \text{ V}; \text{ (see Fig.2)}$ | | | | |
| | BCV26 | | 20000 | _ | _ | |
| | BCV46 | | 10000 | _ | _ | |
| V _{CEsat} | collector-emitter saturation voltage | $I_C = -100 \text{ mA}; I_B = -0.1 \text{ mA}$ | _ | _ | -1 | ٧ |
| V _{BEsat} | base-emitter saturation voltage | $I_C = -100 \text{ mA}; I_B = -0.1 \text{ mA}$ | _ | _ | -1.5 | V |
| V _{BEon} | base-emitter on-state voltage | $I_C = -10 \text{ mA}; V_{CE} = -5 \text{ V}$ | _ | _ | -1.4 | V |
| f_{T} | transition frequency | $I_C = -30 \text{ mA}; V_{CE} = -5 \text{ V}; f = 100 \text{ MHz}$ | _ | 220 | _ | MHz |



PNP Darlington transistors

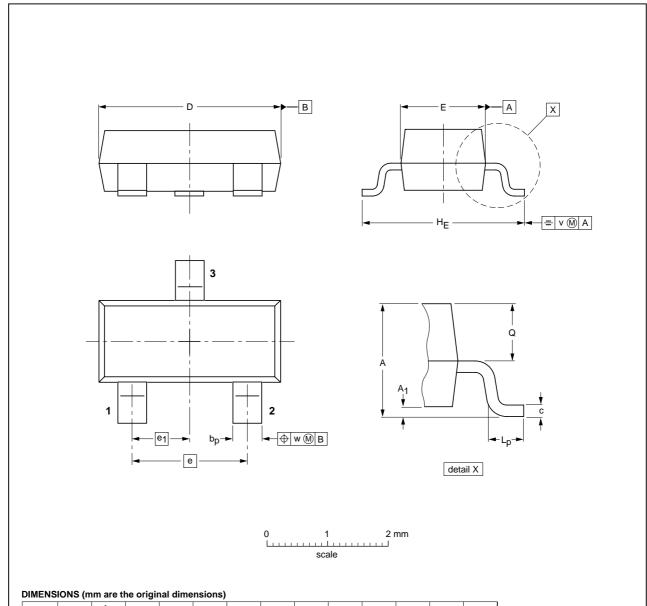
BCV26; BCV46

PACKAGE OUTLINE

UNIT

Plastic surface-mounted package; 3 leads

SOT23



| OUTLINE | REFERENCES | | EUROPEAN | ICCUE DATE | | |
|---------|------------|----------|----------|------------|------------|-----------------------------------|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE |
| SOT23 | | TO-236AB | | | | -04-11-04- 06-03-16 |

 L_p

0.45

0.55

0.1

 $\mathbf{H}_{\mathbf{E}}$

2004 Jan 13 5

bp

0.38

max

0.9

PNP Darlington transistors

BCV26; BCV46

DATA SHEET STATUS

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|-----------------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

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Printed in The Netherlands R75/05/pp7 Date of release: 2004 Jan 13 Document order number: 9397 750 12401

